NSN 5962-01-415-1213

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View Online at https://aerobasegroup.com/nsn/5962-01-415-1213

view Online at https://aerobasegroup.com/hsh/5962-01-415-1213
Body Length:
Between 0.817 inches and 0.833 inches
Body Width:
Between 0.395 inches and 0.405 inches
Body Height:
Between 0.080 inches and 0.100 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-16 modular mission computer core cluster
Features Provided:
Electrostatic sensitive
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Criticality Code Justification:
Cbbl
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, memory, cache ram, 16k x 9 x 2
Voltage Rating And Type Per Characteristic:
4.5 volts total supply and 5.5 volts total supply
Memory Device Type:
Ram
Special Features:
Bicameral (2 bank) cache ram specifically designed to support split instruction & data caches of r3000 type microprocessors
Test Data Document:
96906-mil-std883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 printed circuit
Shelf Life:
N/a
Unit Of Measure:

No

Demilitarization:

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